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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# H5N2007FN

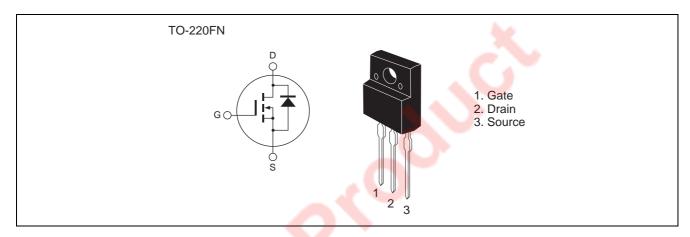
# Silicon N Channel MOS FET High Speed Power Switching

REJ03G0370-0100Z Rev.1.00 May.28.2004

#### **Features**

- Low on-resistance
- Low leakage current
- High speed switching

### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to Source voltage	V <sub>DSS</sub>	200	V
Gate to Source voltage	$V_{GSS}$	±30	V
Drain current	I <sub>D</sub>	25	Α
Drain peak current	I <sub>D (pulse)</sub> Note1	100	Α
Body-Drain diode reverse Drain current	I <sub>DR</sub>	25	Α
Body-Drain diode reverse Drain peak current	I <sub>DR (pulse)</sub> Note1	100	Α
Avalanche current	I <sub>AP</sub> Note3	9	Α
Avalanche energy	E <sub>AR</sub> Note3	5.4	mJ
Channel dissipation	Pch Note2	30	W
Channel to case thermal impedance	θch-c	4.17	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at  $Tc = 25^{\circ}C$ 

3. STch =  $25^{\circ}$ C, Tch  $\leq 150^{\circ}$ C

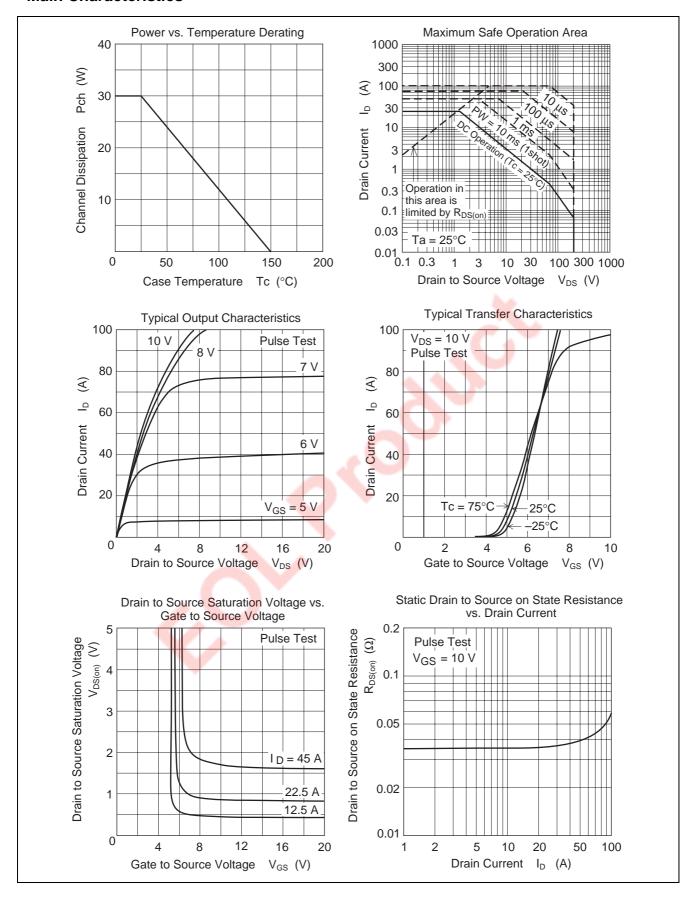
## **Electrical Characteristics**

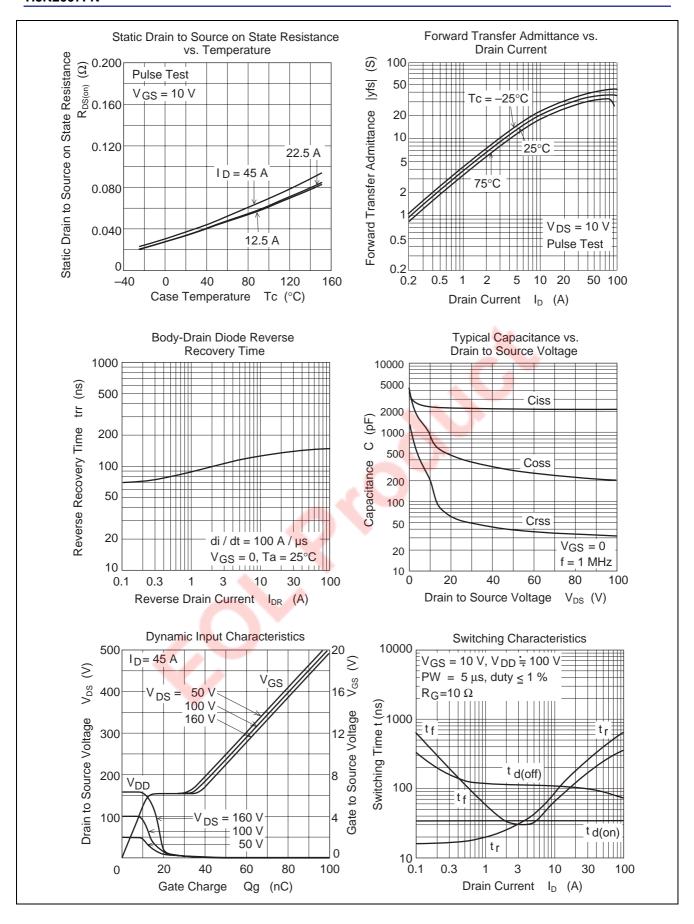
 $(Ta = 25^{\circ}C)$ 

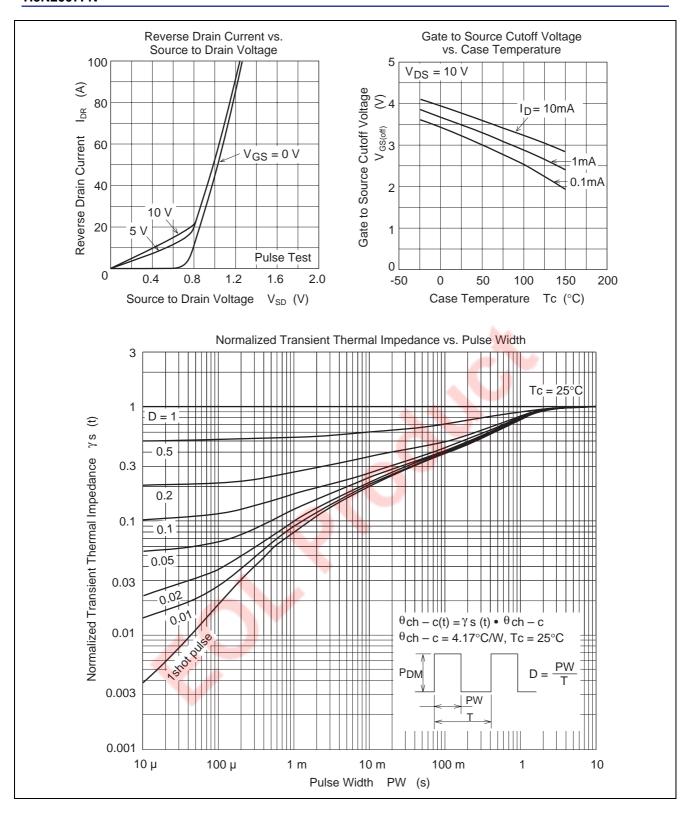
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to Source breakdown voltage	$V_{(BR)DSS}$	200	_	_	٧	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero Gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 200 \text{ V}, V_{GS} = 0$
Gate to Source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to Source cutoff voltage	V <sub>GS(off)</sub>	3.0	_	4.0	٧	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Forward transfer admittance	yfs	13	22	_	S	$I_D = 12.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Static Drain to Source on state resistance	R <sub>DS(on)</sub>	_	0.036	0.047	Ω	$I_D = 12.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	2200	_	pF	V <sub>DS</sub> = 25 V
Output capacitance	Coss	_	410	_	pF	V <sub>GS</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	54	_	pF	
Turn-on delay time	td(on)	_	35	_	ns	I <sub>D</sub> = 12.5 A
Rise time	tr	_	120	_	ns	V <sub>GS</sub> = 10 V
Turn-off delay time	td(off)	_	110	_	ns	$R_{L} = 8 \Omega$ $Rg = 10 \Omega$
Fall time	tf	_	85	_	ns	
Total Gate charge	Qg	_	56	_	nC	V <sub>DD</sub> = 160 V
Gate to Source charge	Qgs	_	13	_	nC	V <sub>GS</sub> = 10 V
Gate to Drain charge	Qgd	_	26	_	nC	$I_D = 25 \text{ A}$
Body-Drain diode forward voltage	$V_{DF}$	_	0.9	1.5	V	$I_F = 25 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-Drain diode reverse recovery time	trr	_	140	_	ns	$I_F = 25 \text{ A}, V_{GS} = 0$ diF/dt = 100 A/ $\mu$ s
Body-Drain diode reverse recovery charge	Qrr	_	0.7		μС	

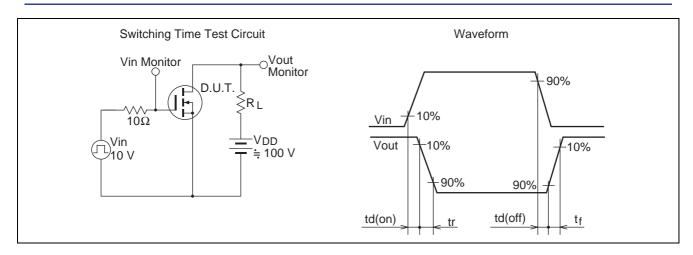
Notes: 4. Pulse test

### **Main Characteristics**



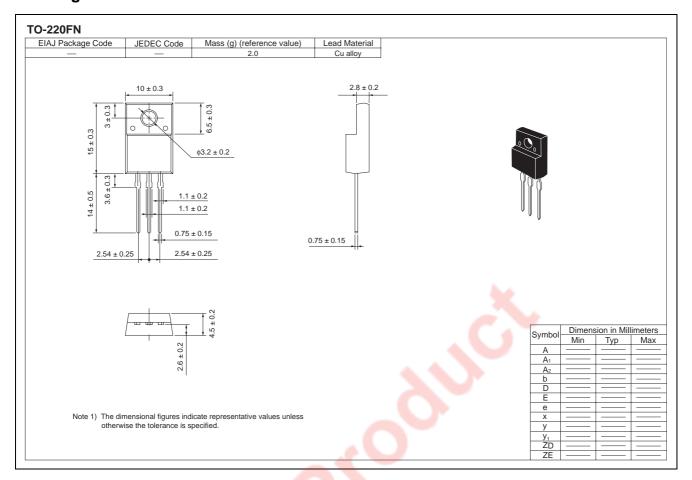








## **Package Dimensions**



## **Ordering Information**

Part Name	Quantity	Shipping Container			
H5N2007FN-E	50 pcs	Plastic magazine			

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